

CMOS 8-Bit Addressable Latch

High-Voltage Types (20-Volt Rating)

■ CD4099B 8-bit addressable latch is a serial-input, parallel-output storage register that can perform a variety of functions.

Data are inputted to a particular bit in the latch when that bit is addressed (by means of inputs A0, A1, A2) and when WRITE DISABLE is at a low level. When WRITE DISABLE is high, data entry is inhibited; however, all 8 outputs can be continuously read independent of WRITE DISABLE and address inputs.

A master RESET input is available, which resets all bits to a logic "0" level when RESET and WRITE DISABLE are at a high level. When RESET is at a high level, and WRITE DISABLE is at a low level, the latch acts as a 1-of-8 demultiplexer; the bit that is addressed has an active output which follows the data input, while all unaddressed bits are held to a logic "0" level.

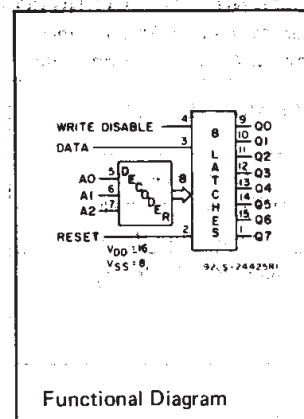
The CD4099B types are supplied in 16-lead hermetic ceramic dual-in-line packages (D and F suffixes), 16-lead plastic dual-in-line packages (E suffix), and in chip form (H suffix).

Features:

- Serial data input
- Active parallel output
- Storage register capability
- Master clear
- Can function as demultiplexer
- Standardized, symmetrical output characteristics
- 100% tested for quiescent current at 20 V
- Maximum input current of 1 μ A at 18 V (full package-temperature range), 100 nA at 18 V and 25°C
- Noise margin (full package-temperature range) = 1 V at $V_{DD} = 5$ V, 2 V at $V_{DD} = 10$ V, 2.5 V at $V_{DD} = 15$ V
- 5-V, 10-V, and 15-V parametric ratings
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE RANGE, (V_{DD})	 -0.5V to +20V
Voltages referenced to V_{SS} Terminal)	
INPUT VOLTAGE RANGE, ALL INPUTS	 -0.5V to $V_{DD} + 0.5$ V
DC INPUT CURRENT, ANY ONE INPUT	 ± 10 mA
POWER DISSIPATION PER PACKAGE (P_D):	
For $T_A = -55^\circ\text{C}$ to $+100^\circ\text{C}$	 500mW
For $T_A = +100^\circ\text{C}$ to $+125^\circ\text{C}$	 Derate Linearly at 12mW/ $^\circ\text{C}$ to 200mW
DEVICE DISSIPATION PER OUTPUT TRANSISTOR	
FOR $T_A = \text{FULL PACKAGE-TEMPERATURE RANGE (All Package Types)}$	 100mW
OPERATING-TEMPERATURE RANGE (T_A)	 -55°C to $+125^\circ\text{C}$
STORAGE TEMPERATURE RANGE (T_{stg})	 -65°C to $+150^\circ\text{C}$
LEAD TEMPERATURE (DURING SOLDERING):	
At distance 1/16 $\pm$ 1/32 inch (1.59 $\pm$ 0.79mm) from case for 10s max	 $+265^\circ\text{C}$



Applications:

- Multi-line decoders
- A/D converters

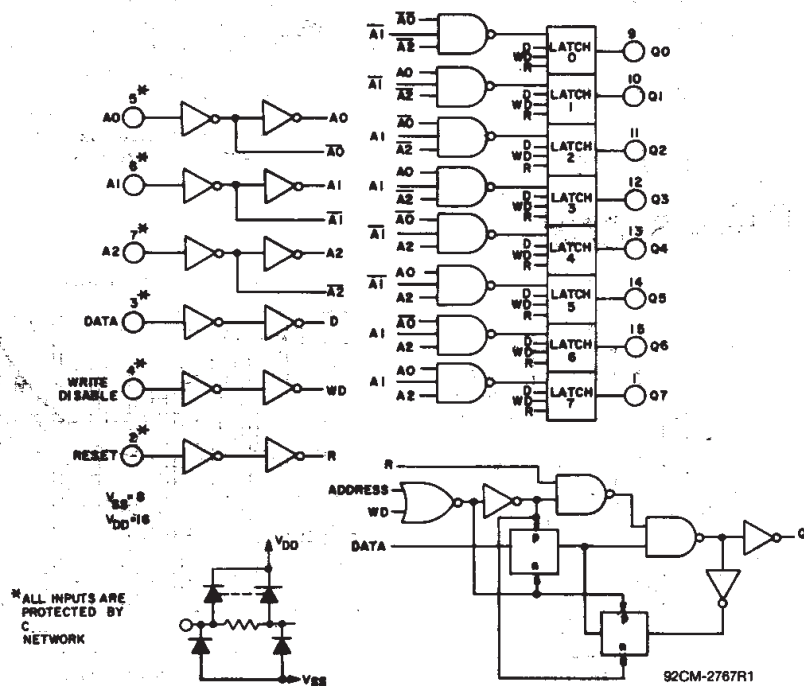


Fig. 1 — Logic diagram of CD4099B and detail of 1 of 8 latches.

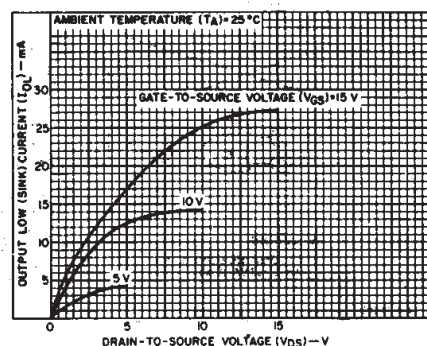
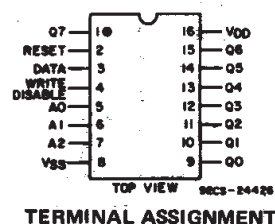


Fig. 2 — Typical output low (sink) current characteristics.

CD4099B Types

RECOMMENDED OPERATING CONDITIONS at $T_A = 25^\circ\text{C}$ (Unless otherwise specified)
For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges.

CHARACTERISTIC	SEE FIG. 15*	V _{DD} (V)	LIMITS		UNITS
			MIN.	MAX.	
Supply Voltage Range: (At T_A = Full Package Temperature Range)			3	18	V
Minimum Pulse Width, t_W Data	4	5	200	—	ns
		10	100	—	
		15	80	—	
Address	8	5	400	—	
		10	200	—	
		15	125	—	
Reset	5	5	150	—	
		10	75	—	
		15	50	—	
Setup Time, t_S Data to WRITE DISABLE	6	5	100	—	ns
		10	50	—	
		15	35	—	
Hold Time, t_H Data to WRITE DISABLE	7	5	150	—	ns
		10	75	—	
		15	50	—	

* Circled numbers refer to times indicated on master timing diagram.

Note: In addition to the above characteristics, a WRITE DISABLE ON time (the time that WRITE DISABLE is at a high level) must be observed during an address change for the total time that the external address lines A0, A1, and A2 are settling to a stable level, to prevent a wrong cell from being addressed (see Fig. 3).

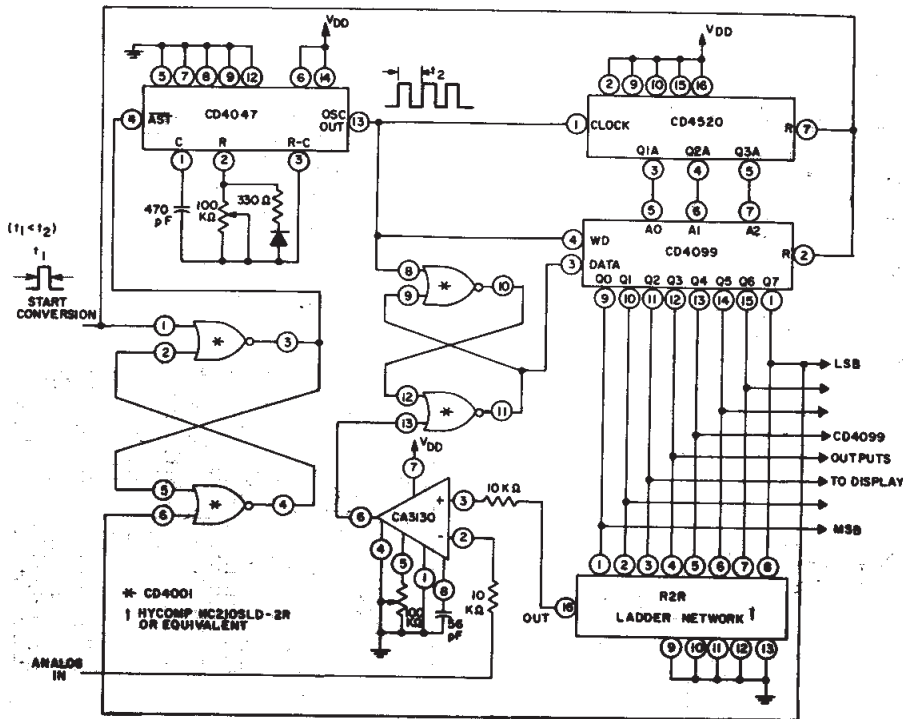


Fig. 5 — A/D converter

MODE SELECTION			
WD	R	ADDRESSED LATCH	UNADDRESSED LATCH
0	0	Follows Data	Holds Previous State
0	1	Follows Data (Active High 8-Channel Demultiplexer)	Reset to "0"
1	0	Holds Previous State	Reset to "0"
1	1	Reset to "0"	Reset to "0"

WD = WRITE DISABLE

R = RESET

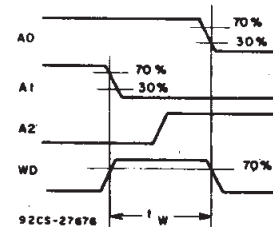


Fig. 3 — Definition of WRITE DISABLE ON time.

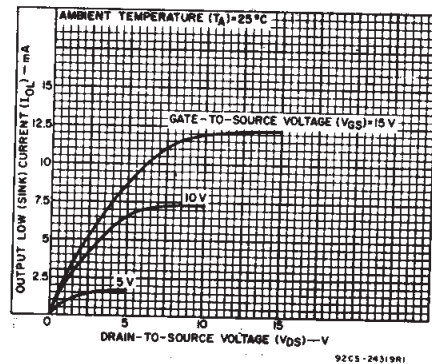


Fig. 4 — Minimum output low (sink) current characteristics.

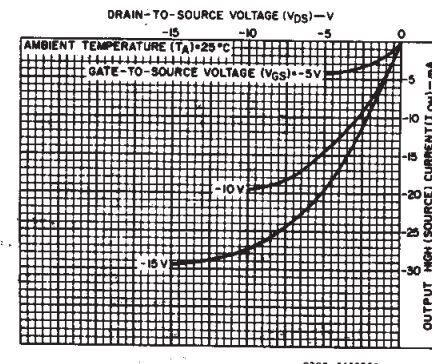
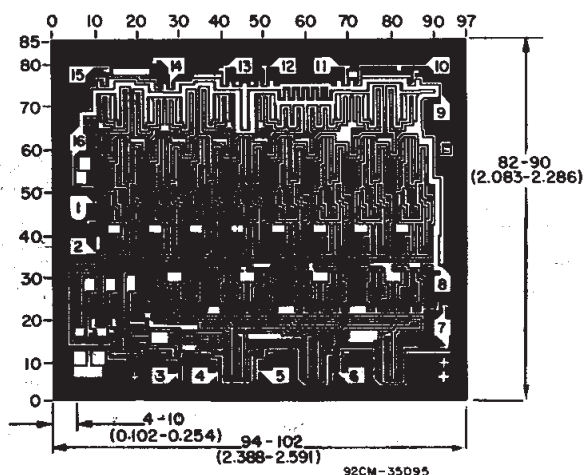


Fig. 6 — Typical output high (source) current characteristics.

CD4099B Types

STATIC ELECTRICAL CHARACTERISTICS

CHARACTER- ISTIC	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)							UNITS
	V _O (V)	V _{IN} (V)	V _{DD} (V)					+25			
				-55	-40	+85	+125	Min.	Typ.	Max.	
Quiescent Device Current, I _{DD} Max.	—	0,5	5	5	5	150	150	—	0.04	5	μA
	—	0,10	10	10	10	300	300	—	0.04	10	
	—	0,15	15	20	20	600	600	—	0.04	20	
	—	0,20	20	100	100	3000	3000	—	0.08	100	
Output Low (Sink) Current I _{OL} Min.	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1	—	mA
	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6	—	
	1.5	0,15	15	4.2	4	2.8	2.4	3.4	6.8	—	
Output High (Source) Current, I _{OH} Min.	4.6	0,5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	—	mA
	2.5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	—	
	9.5	0,10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	—	
	13.5	0,15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	—	
Output Voltage: Low-Level, V _{OL} Max.	—	0,5	5	0.05				—	0	0.05	V
	—	0,10	10	0.05				—	0	0.05	
	—	0,15	15	0.05				—	0	0.05	
Output Voltage: High-Level, V _{OH} Min.	—	0,5	5	4.95				4.95	5	—	V
	—	0,10	10	9.95				9.95	10	—	
	—	0,15	15	14.95				14.95	15	—	
Input Low Voltage, V _{IL} Max.	0.5, 4.5	—	5	1.5				—	—	1.5	V
	1, 9	—	10	3				—	—	3	
	1.5,13.5	—	15	4				—	—	4	
Input High Voltage, V _{IH} Min.	0.5, 4.5	—	5	3.5				3.5	—	—	V
	1, 9	—	10	7				7	—	—	
	1.5,13.5	—	15	11				11	—	—	
Input Current I _{IN} Max.	—	0,18	18	±0.1	±0.1	±1	±1	—	±10 ⁻⁵	±0.1	μA



CD4099BH
DIMENSIONS AND PAD LAYOUT

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10⁻³ inch).

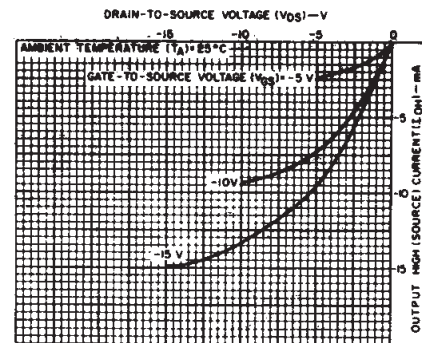


Fig. 7 — Minimum output high (source) current characteristics.

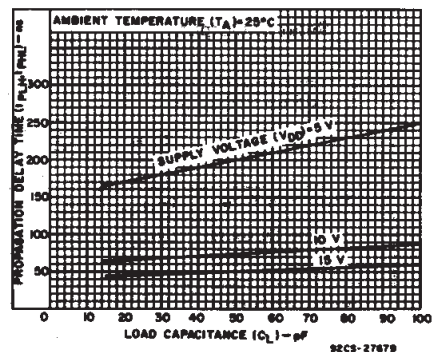


Fig. 8 — Typical propagation delay time (data to Qn) vs. load capacitance.

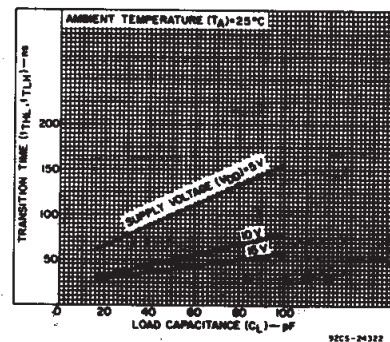


Fig. 9 — Typical transition time vs. load capacitance.

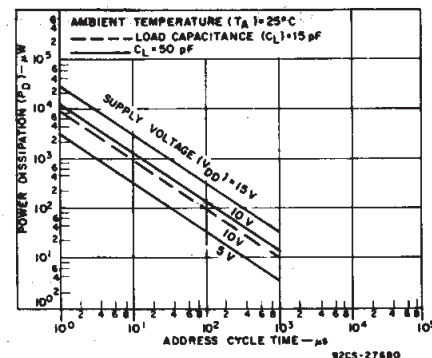


Fig. 10 — Typical dynamic power dissipation vs. address cycle time.

CD4099B Types

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, $C_L = 50\text{ pF}$,
Input $t_r, t_f = 20\text{ ns}$, $R_L = 200\text{ k}\Omega$

CHARACTERISTIC	CONDITIONS		LIMITS		UNITS
	SEE	V_{DD} (V)	TYP.	MAX.	
Propagation Delay: t_{PLH} , t_{PHL}	①	5	200	400	ns
		10	75	150	
		15	50	100	
Data to Output, WRITE DISABLE to Output, t_{PLH} , t_{PHL}	②	5	200	400	
		10	80	160	
		15	60	120	
Reset to Output, t_{PHL}	③	5	175	350	ns
		10	80	160	
		15	65	130	
Address to Output, t_{PLH} , t_{PHL}	⑨	5	225	450	
		10	100	200	
		15	75	150	
Transition Time, (Any Output) t_{THL} , t_{TLH}		5	100	200	ns
		10	50	100	
		15	40	80	
Minimum Pulse Width, t_W Data	④	5	100	200	ns
		10	50	100	
		15	40	80	
Address	⑧	5	200	400	ns
		10	100	200	
		15	65	125	
Reset	⑤	5	75	150	ns
		10	40	75	
		15	25	50	
Minimum Setup Time, t_S Data to WRITE DISABLE	⑥	5	50	100	ns
		10	25	50	
		15	20	35	
Minimum Hold Time, t_H Data to WRITE DISABLE	⑦	5	75	150	ns
		10	40	75	
		15	25	50	
Input Capacitance, C_{IN}	Any Input		5	7.5	pF

*Circled numbers refer to times indicated on master timing diagram.

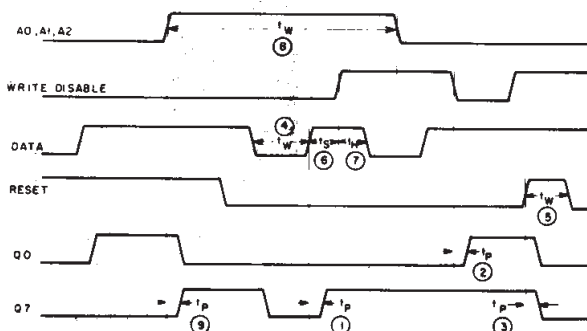


Fig. 15 — Master timing diagram.

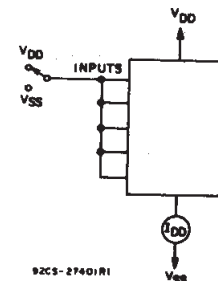


Fig. 11 — Quiescent device current test circuit.

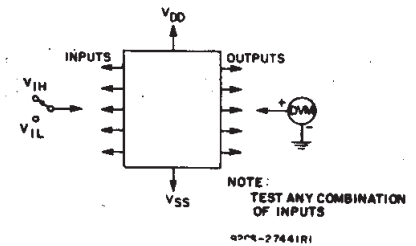


Fig. 12 — Input voltage test circuit.

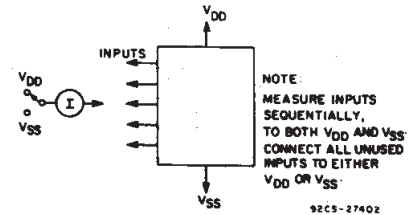


Fig. 13 — Input current test circuit.

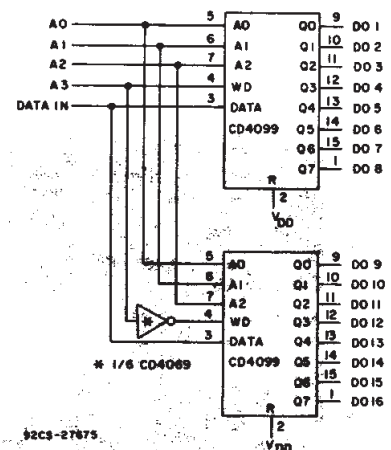


Fig. 14 — 1 of 16 decoder/demultiplexer.

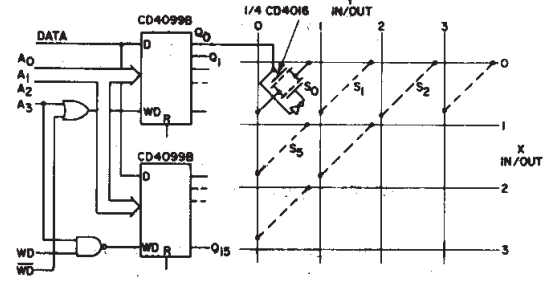


Fig. 16 — Multiple selection decoding — 4 x 4 crosspoint switch.

IMPORTANT NOTICE

Texas Instruments and its subsidiaries (TI) reserve the right to make changes to their products or to discontinue any product or service without notice, and advise customers to obtain the latest version of relevant information to verify, before placing orders, that information being relied on is current and complete. All products are sold subject to the terms and conditions of sale supplied at the time of order acknowledgement, including those pertaining to warranty, patent infringement, and limitation of liability.

TI warrants performance of its semiconductor products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

CERTAIN APPLICATIONS USING SEMICONDUCTOR PRODUCTS MAY INVOLVE POTENTIAL RISKS OF DEATH, PERSONAL INJURY, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE ("CRITICAL APPLICATIONS"). TI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS. INCLUSION OF TI PRODUCTS IN SUCH APPLICATIONS IS UNDERSTOOD TO BE FULLY AT THE CUSTOMER'S RISK.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards must be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance or customer product design. TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used. TI's publication of information regarding any third party's products or services does not constitute TI's approval, warranty or endorsement thereof.

Copyright © Each Manufacturing Company.

All Datasheets cannot be modified without permission.

This datasheet has been download from :

www.AllDataSheet.com

100% Free DataSheet Search Site.

Free Download.

No Register.

Fast Search System.

www.AllDataSheet.com